PATENT APPLICATION

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

ATTORNEY DOCKET NO. TSM03-0511

As a below named inventor, I hereby declare that my residence/post office address and citizenship are as stated below next to my name; That I verily believe that I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled as set (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled as set (or plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled as set (if plural names are listed below) of the subject matter which is claimed and understand the contents of the specification, forth below, which is described in the attached specification; that I have reviewed and understand the contents of the specification, forth below, which is described in the attached specification; that I have reviewed and understand the contents of the specification, forth below, which is described in the attached specification; that I have reviewed and understand the contents of the specification, forth below, which is described by any amendment(s) referred to in the oath or declaration; that no application for patent or inventor's including the claims, as amended by any amendment(s) referred to in the oath or declaration; that no application for patent or inventor's including the claims, as amended by any amendment(s) referred to in the oath or declaration; that no application for patent or inventor's including the claims, as amended by any amendment(s) referred to in the oath or declaration; that no application for patent or inventor's including the claims, as amended by any amendment(s) referred to in the oath or declaration; that no application for patent or inventor's including the claims, as amended by any amendment(s) referred to in the oath or declaration; that no application for patent or inv

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Title of Invention:	Multiple-Gate Transistors F	ormed on Bulk Substrates
	attamen(s) and/or agent(s) li	isted below to prosecute this application and transact all business in the Patent and
Power of Attorney:	I hereby appoint the following autometed therewith.	·
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Date: Sep. 10, 2003	Gent 15. 2003	Sept. 17, 200)	
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TSM03-0511

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Page 1 of 1

Declaration and Power of Attorney